

## JA05004000P47; 500 - 4000 MHz 50 W AMPLIFIER

- Solid-state Class AB design
- **Ultra wide-band Operation**  $\bigcirc$
- GaN on SiC Transistors 0
- High reliability and ruggedness 0
- Forward/Reflected Power Monitoring
- Fast Switching Capability



Frequency: 500-4000 MHz

**Output Power:** 50 W typ. 45 W min. @ 600-3800MHz

> 25 W min. @ 500 MHz-600 MHz 25 W min. @ 3800 MHz-4000 MHz

RF input for Rated Output: 0 dBm typ. Nominal Gain (@ SS input): 47 ± 4 dB typ.

**Input VSWR:** 2:1 max.

**Load VSWR for Survival:** ∞:1 (Fully Protected)

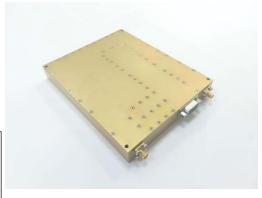
**DC Supply Voltage:** 30 V

**Enable Speed:** 5 µs max.

-40 °C to 85 °C **Operating Case Temp.:** 

External Heatsink Required

-40 °C to 85 °C **Storage Temperature:** 



## **INTERFACES**

RF Input: **SMA Female** 

RF Output: **SMA Female** 

9-PIN DSUB: 1) GND

2) GND 3) 30 V 4) Enable

5) Reverse Power

6) GND 7) 30 V 8) 30 V

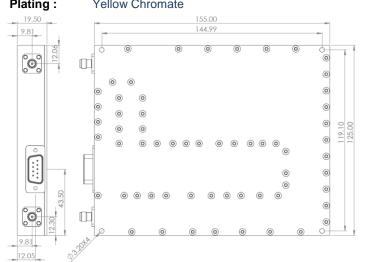
9) Forward Power

## MECHANICAL SPECIFICATIONS

Size (mm): 155 × 125 × 19.5 6.1 x 4.9 x 0.77 (inch):

Weight: 675 gr.

Plating: Yellow Chromate



## GENERAL DESCRIPTION

RFTR's JA05004000P47 is reliable ultrawide-band 50W power amplifier operating between 500-4000 MHz and suitable for CW or Pulsed waveforms. This amplifier can be used in different applications such as radars, datalinks, mobile jamming or UAVs in S and L bands. JA05004000P47 offers forward-reverse power monitoring and survives under ∞:1 load **VSWR** condition. The PΑ can enabled/disabled as fast as 5 µs that makes it suitable for power saving during pulsed applications.

JA05004000P47 is designed with the components that do not require any export license.

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